

Microsemi.

Power Matters[™]

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Overview Diagrams

 Electrical Rating
 Symbol
 Min
 Typ
 Max
 Unit

 DC Current Gain
 HFE
 40.00
 250.00

 Turn Off Time (nS)
 t_{off}
 25.00
 ns

Maximum Electrical Rating	Symbol	Min	Тур	Max	Unit
Collector Current (dc)	I _C			0.10	Α
Collector-Emitter Voltage (Base Open)	V _{CEO}			20.00	V
Junction Temperature (°C)	T_J			200.00	°C

This part can be found in the following product categories:

- Non-Radiation Hardened Devices ▶ Transistors ▶ BJT(BiPolar Junction Transistor) ▶ NPN Transistor
- Discretes ► Transistors ► BJT(BiPolar Junction Transistor) ► NPN Transistor

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